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## CLAIMS:

1. An electric or electronic circuit arrangement (100) for protecting at least a chip arrangement (200), for example, at least a (semiconductor) chip arrangement, particularly at least a controller chip arrangement for a chip card or smart card, from manipulation and/or abuse, characterized by

at least one, particularly optosensitive detector unit (10), whose output voltage ( $V_{out}$ ) is a measure of the incidence of light ( $L_i$ ) on the detector unit (10), and

at least one comparator unit (20) preceded by the detector unit (10) provided for comparing the output voltage ( $V_{out}$ ) of the detector unit (10) with a reference voltage ( $V_{ref}$ ), wherein the data and/or functions of the chip arrangement (200) to be protected can be temporarily or permanently obstructed and/or erased (L) and/or blocked (S) and/or interrupted in the case of a failure message occurring during comparison of the output voltage ( $V_{out}$ ) of the detector unit (10) with the reference voltage ( $V_{ref}$ ).

2. A circuit arrangement (100) as claimed in claim 1, characterized in that the detector unit (10) is arranged underneath the surface of the chip arrangement (200), particularly underneath at least an oxide layer of the chip arrangement (200), and/or substantially in the plane of the data and/or functions to be protected.

3. A circuit arrangement (100) as claimed in claim 1 or 2, characterized in that the detector unit (10) comprises at least one bipolar transistor (12), particularly at least one pnp transistor.

4. A circuit arrangement (100) as claimed in claim 3, characterized in that the detector unit (10) is constituted by a plurality or a large number of spatially arranged bipolar transistors (12).

12. A circuit arrangement (100) as claimed in any one of claims 1 to 11, characterized in that

the working point of the detector unit (10) and/or

the threshold value of the reference voltage ( $V_{ref}$ ) is adjustable.

13. A circuit arrangement (100) as claimed in any one of claims 1 to 12, characterized in that at least a dielectric coating, particularly an insulation layer and/or passivation layer and/or a further protective coating which is provided for protecting the chip arrangement (200) from external influences and preferably cannot be easily removed is arranged within the chip arrangement (200) and/or laterally to the chip arrangement (200) and/or on the chip arrangement (200).

14. A circuit arrangement (100) as claimed in claim 13, characterized in that the material of the dielectric coating is epoxy resin or silicon nitride ( $\text{SiNO}_2$ ) or silicon dioxide ( $\text{SiO}_2$ ), or other insulating materials used in the manufacture of semiconductors.

15. A circuit arrangement (100) as claimed in claim 13 or 14, characterized in that the material of the dielectric coating is substantially opaque.

16. A circuit arrangement (100) as claimed in any one of claims 1 to 15, characterized in that the chip arrangement (200) is arranged on at least a particularly layered carrier substrate of a semiconducting or insulating material.

17. A circuit arrangement (100) as claimed in any one of claims 1 to 16, characterized in that the circuit arrangement (100) is implemented and/or integrated in at least a card, particularly in at least a chip card or in at least a smart card.

18. A card, particularly a chip card or smart card, comprising at least an electric or electronic circuit arrangement (100) as claimed in any one of claims 1 to 17.

19. A chip arrangement (200), for example a (semiconductor) chip arrangement, particularly a controller chip arrangement for a chip card or smart card, the chip arrangement comprising

at least one, preferably a plurality or a large number of particularly optosensitive detector units (10) as claimed in any one of claims 1 to 20, and at least a combination logic unit (40) for combining the detector units (10).

*Sub 12*  
20. A chip arrangement (200) as claimed in claim 19, characterized in that the combination logic unit (40) is connected to at least a control logic unit (50).

*Sub 15*  
21. A chip arrangement (200) as claimed in claim 19 or 20, characterized in that the combination logic unit (40) is connected to at least a particularly electrically erasable storage unit (60).

*Sub 15*  
22. A chip arrangement (200) as claimed in claim 21, characterized in that the storage unit (60) is constituted by at least an EEPROM storage unit (60') (EEPROM = Electrically Erasable Programmable Read-Only Memory), and the data and/or functions of the chip arrangement (200) to be protected are erasable (L) when a failure message by means of the EEPROM storage unit (60') occurs particularly during comparison of the output voltage ( $V_{out}$ ) of the detector unit (10) with the reference voltage ( $V_{ref}$ ).

*Sub 15*  
23. A chip arrangement (200) as claimed in claim 20, 21 or 22, characterized in that  
the storage unit (60) is arranged between the combination logic unit (40) and the control logic unit (50), and  
the access to the data and/or functions of the chip arrangement (200) to be protected can be blocked by blocking (S) the storage unit (60) when a failure message occurs particularly during comparison of the output voltage ( $V_{out}$ ) of the detector unit (10) with the reference voltage ( $V_{ref}$ ).

*Sub 15*  
24. A chip arrangement (200) as claimed in any one of claims 19 to 23,  
25 characterized in that the chip arrangement (200) can be permanently short-circuited via the power supply voltage ( $V_{dd}$ ), particularly via the power supply terminals of the chip arrangement (200).

*Sub 15*  
25. A method of protecting at least a chip arrangement (200), for example at least a (semiconductor) chip arrangement, particularly at least a controller chip arrangement for a chip card or smart card from manipulation and/or abuse, characterized in that  
an output voltage ( $V_{out}$ ) determined by light ( $L_i$ ) incident on the detector unit (10) is generated in at least a particularly optosensitive detector unit (10), particularly in at least a bipolar transistor (12);

the output voltage ( $V_{out}$ ) of the detector unit (10) is compared with a reference voltage ( $V_{ref}$ ) in at least a comparator unit (20) preceded by the detector unit (10), and the data and/or functions of the chip arrangement (200) to be protected are temporarily or permanently obstructed and/or erased (L) and/or blocked (S) and/or interrupted when a failure message is generated during comparison of the output voltage ( $V_{out}$ ) of the detector unit (10) with the reference voltage ( $V_{ref}$ ).

26. A method as claimed in claim 25, characterized in that the light incident on the detector unit (10) is substantially absorbed by means of the junction between the base (122) of the bipolar transistor (12) and the collector (126) of the bipolar transistor (12).

27. A method as claimed in claim 25 or 26, characterized in that the failure message is triggered in the comparator unit (20) when the output voltage ( $V_{out}$ ) of the detector unit (10) deviates from the nominal range.

28. A method as claimed in any one of claims 25 to 27, characterized in that the triggering of the failure message is adjusted by means of the working point of the detector unit (10) and/or the threshold value of the reference voltage ( $V_{ref}$ ).

29. A method as claimed in any one of claims 25 to 28, characterized in that the failure message is generated in at least an evaluation unit (30) implemented and/or integrated in the comparator unit (20), or an evaluation unit (30) preceded by the comparator unit (20).

30. A method as claimed in any one of claims 25 to 29, characterized in that at least a control logic unit (50) connected to at least a combination logic unit (40) provided for combining the detector units (10) is temporarily blocked (S) when the failure message is triggered.

31. A method as claimed in any one of claims 25 to 29, characterized in that at least an electrically erasable storage unit (60) arranged between at least a combination logic

unit (40) provided for combining the detector units (10) and at least a control logic unit (50) is permanently blocked (S) when the failure message is triggered.

32. A method as claimed in claim 31, characterized in that the control logic unit (50) is temporarily or permanently blocked (S) by means of at least a "reset" (RS).

33. A method as claimed in any one of claims 25 to 29, characterized in that a particularly once-electrically programmable storage unit (60) connected to at least a combination logic unit (40) provided for combining the detector units (10) is permanently blocked (S) when the failure message is triggered.

34. A method as claimed in claim 33, characterized in that the power supply voltage ( $V_{dd}$ ) is short-circuited by means of the storage unit (60), and particularly the power supply terminals of the chip arrangement (200) are short-circuited.

35. A method as claimed in any one of claims 25 to 29, characterized in that the data and/or functions to be protected are erased (L) in an EEPROM storage unit (60') (EEPROM = Electrically Erasable Programmable Read-Only Memory) connected to at least a combination logic unit (40) provided for combining the detector units (10) when the failure message is triggered.